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1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage	80	V
V_{GS}	Gate-source voltage	± 20	V
I_D	Drain current (continuous) at $T_C = 25\text{ }^{\circ}\text{C}$	90 ⁽¹⁾	A
I_D	Drain current (continuous) at $T_C = 100\text{ }^{\circ}\text{C}$	90	A
I_{DM} ⁽²⁾	Drain current (pulsed)	360	A
P_{TOT}	Total dissipation at $T_C = 25\text{ }^{\circ}\text{C}$	200	W
E_{AS} ⁽³⁾	Single pulse avalanche energy	515	mJ
T_j	Operating junction temperature	- 55 to 175	$^{\circ}\text{C}$
T_{stg}	Storage temperature		

Notes:

⁽¹⁾Limited by package

⁽²⁾Pulse width is limited by safe operating area

⁽³⁾Starting $T_j = 25\text{ }^{\circ}\text{C}$, $I_D = 18.5\text{ A}$, $V_{DD} = 50\text{ V}$

Table 3: Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-pcb}$ ⁽¹⁾	Thermal resistance junction-pcb	35	$^{\circ}\text{C/W}$
$R_{thj-case}$	Thermal resistance junction-case	0.75	$^{\circ}\text{C/W}$

Notes:

⁽¹⁾When mounted on FR-4 board of 1inch², 2oz Cu

2 Electrical characteristics

(T_{CASE} = 25 ° C unless otherwise specified)

Table 4: On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	V _{GS} = 0, I _D = 250 μA	80			V
I _{DSS}	Zero gate voltage Drain current	V _{GS} = 0, V _{DS} = 80 V			1	μA
		V _{GS} = 0, V _{DS} = 80 V, T _J = 125 ° C			10	μA
I _{GSS}	Gate-source leakage current	V _{DS} = 0, V _{GS} = ± 20 V			± 100	nA
V _{GS(th)}	Gate threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.5		4.5	V
R _{DS(on)}	Static drain-source on-resistance	V _{GS} = 10 V, I _D = 45 A		3.3	4	mΩ

Table 5: Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C _{iss}	Input capacitance	V _{GS} = 0, V _{DS} = 40 V, f = 1 MHz	-	6340	-	pF
C _{oss}	Output capacitance		-	1195	-	pF
C _{rss}	Reverse transfer capacitance		-	105	-	pF
Q _g	Total gate charge	V _{DD} = 40 V, I _D = 64 A, V _{GS} = 10 V	-	96	-	nC
Q _{gs}	Gate-source charge		-	30	-	nC
Q _{gd}	Gate-drain charge		-	26	-	nC

Table 6: Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t _{d(on)}	Turn-on delay time	V _{DD} = 40 V, I _D = 45 A R _G = 4.7 Ω, V _{GS} = 10 V	-	26	-	ns
t _r	Rise time		-	51	-	ns
t _{d(off)}	Turn-off-delay time		-	82	-	ns
t _f	Fall time		-	44	-	ns

Table 7: Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD}	Source-drain current		-		90	A
$I_{SDM}^{(1)}$	Source-drain current (pulsed)		-		360	A
$V_{SD}^{(2)}$	Forward on voltage	$V_{GS} = 0, I_{SD} = 90 \text{ A}$	-		1.2	V
t_{rr}	Reverse recovery time	$I_{SD} = 64 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s},$ $V_{DD} = 60 \text{ V}$ $T_j = 150^\circ \text{C}$	-	58		ns
Q_{rr}	Reverse recovery charge		-	92		nC
I_{RRM}	Reverse recovery current		-	3.2		A

Notes:

⁽¹⁾Pulse width is limited by safe operating area

⁽²⁾Pulse test: pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)

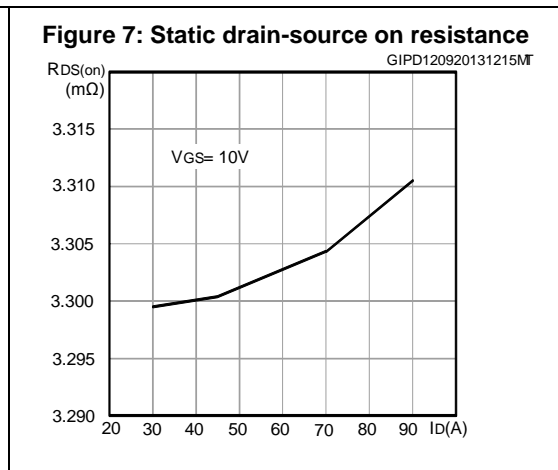
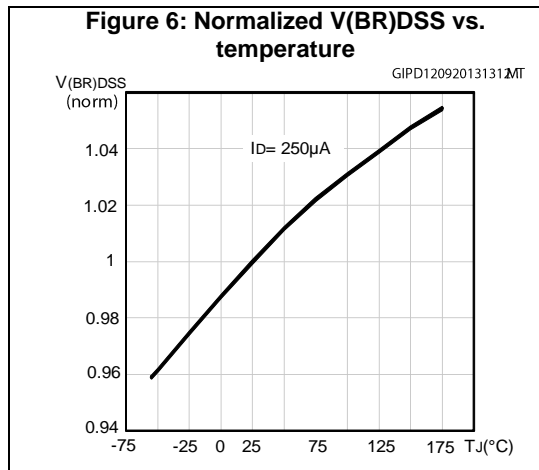
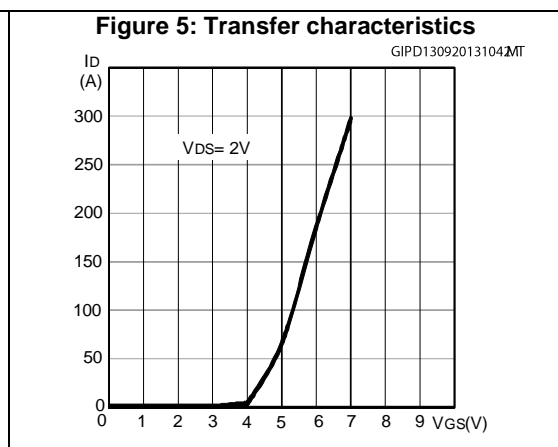
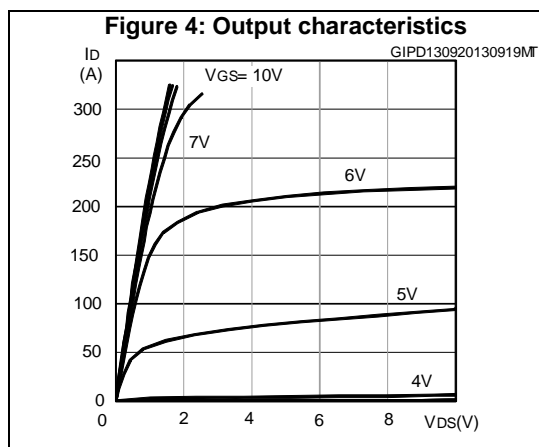
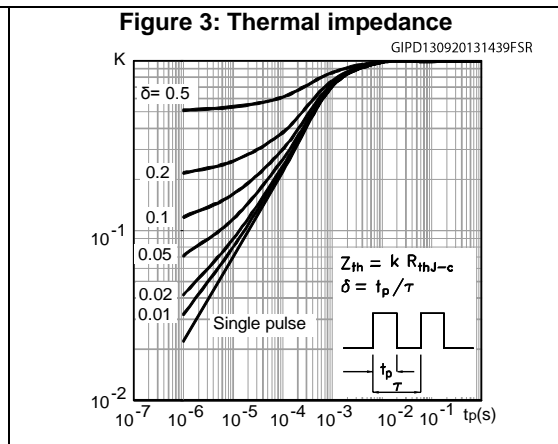
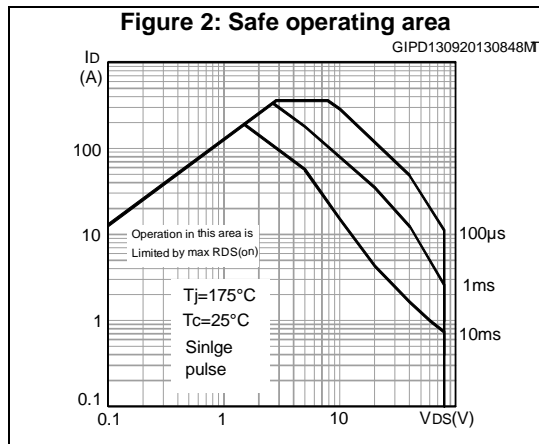


Figure 8: Gate charge vs. gate-source voltage

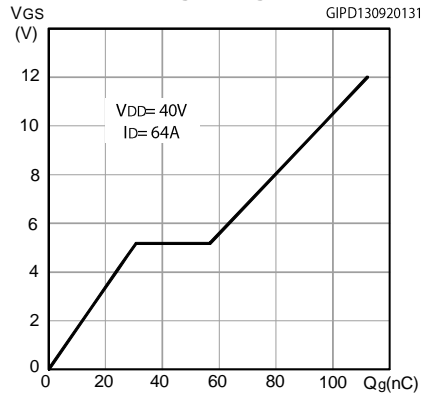


Figure 9: Capacitance variations

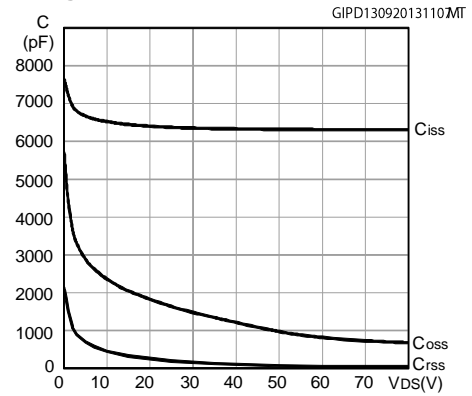


Figure 10: Normalized gate threshold voltage vs. temperature

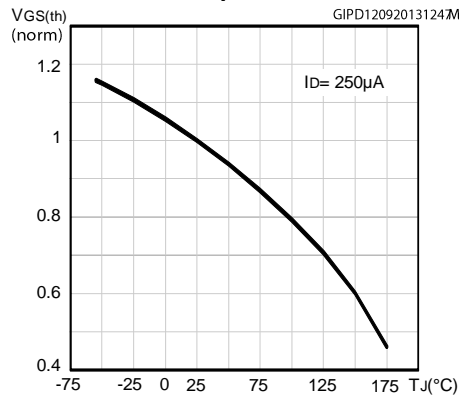


Figure 11: Normalized on resistance vs. temperature

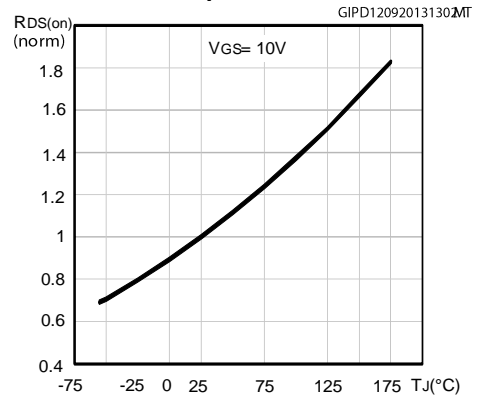
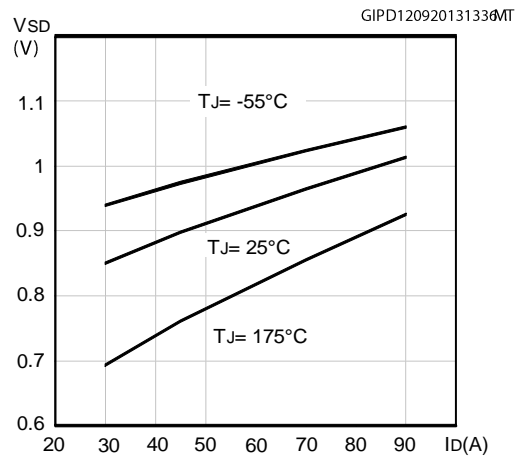
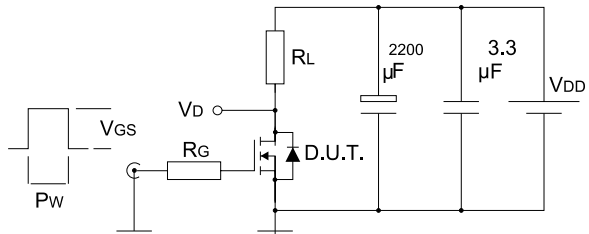


Figure 12: Source-drain diode forward characteristics



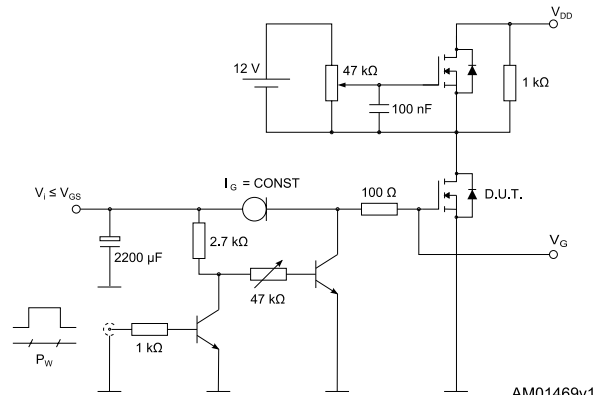
3 Test circuits

Figure 13: Switching times test circuit for resistive load



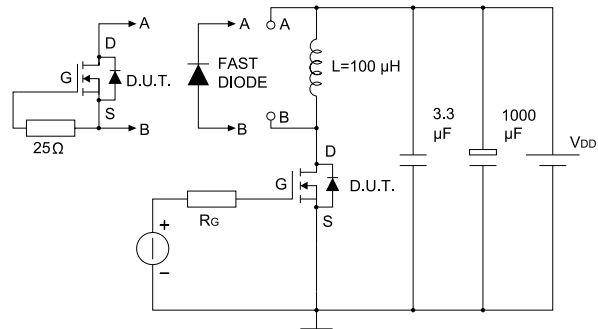
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Figure 14: Gate charge test circuit



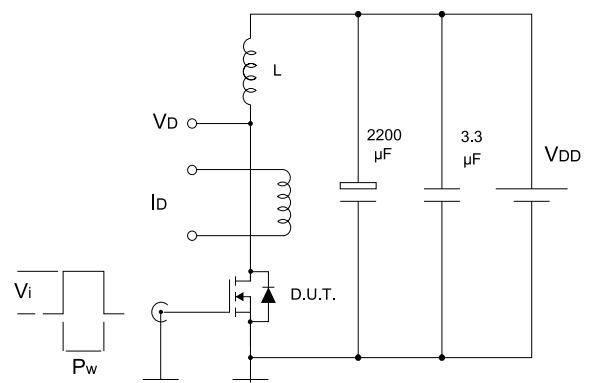
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Figure 15: Test circuit for inductive load switching and diode recovery times



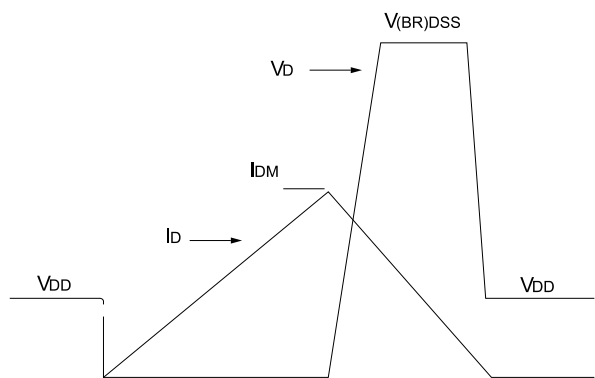
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Figure 16: Unclamped inductive load test circuit



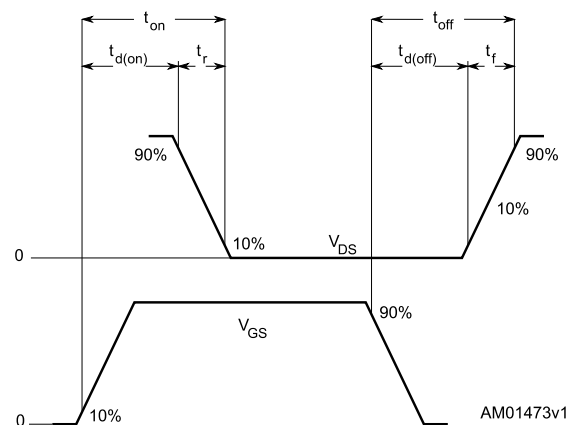
AM01471v1

Figure 17: Unclamped inductive waveform



AM01472v1

Figure 18: Switching time waveform



AM01473v1

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

4.1 H²PAK-2 package information

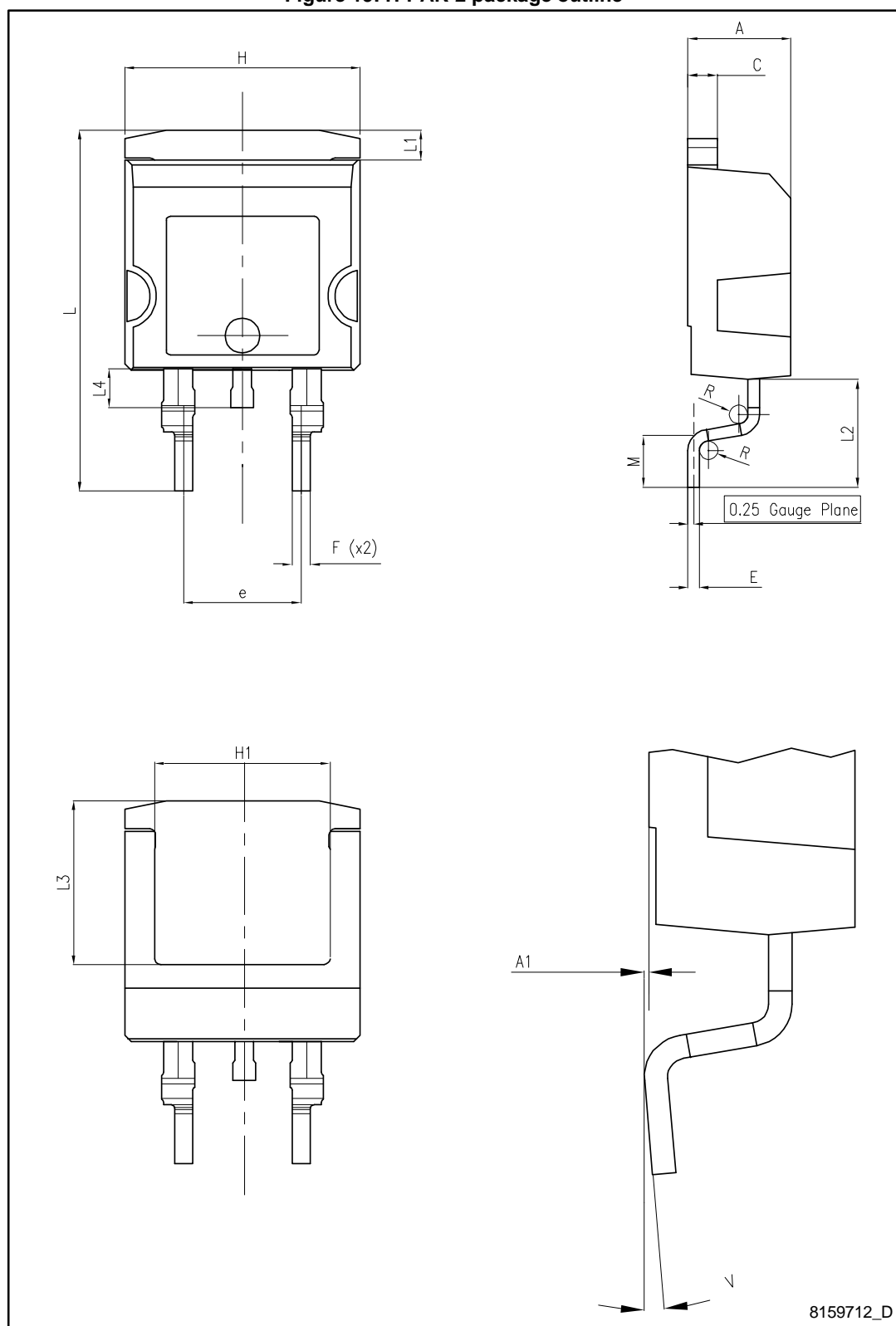
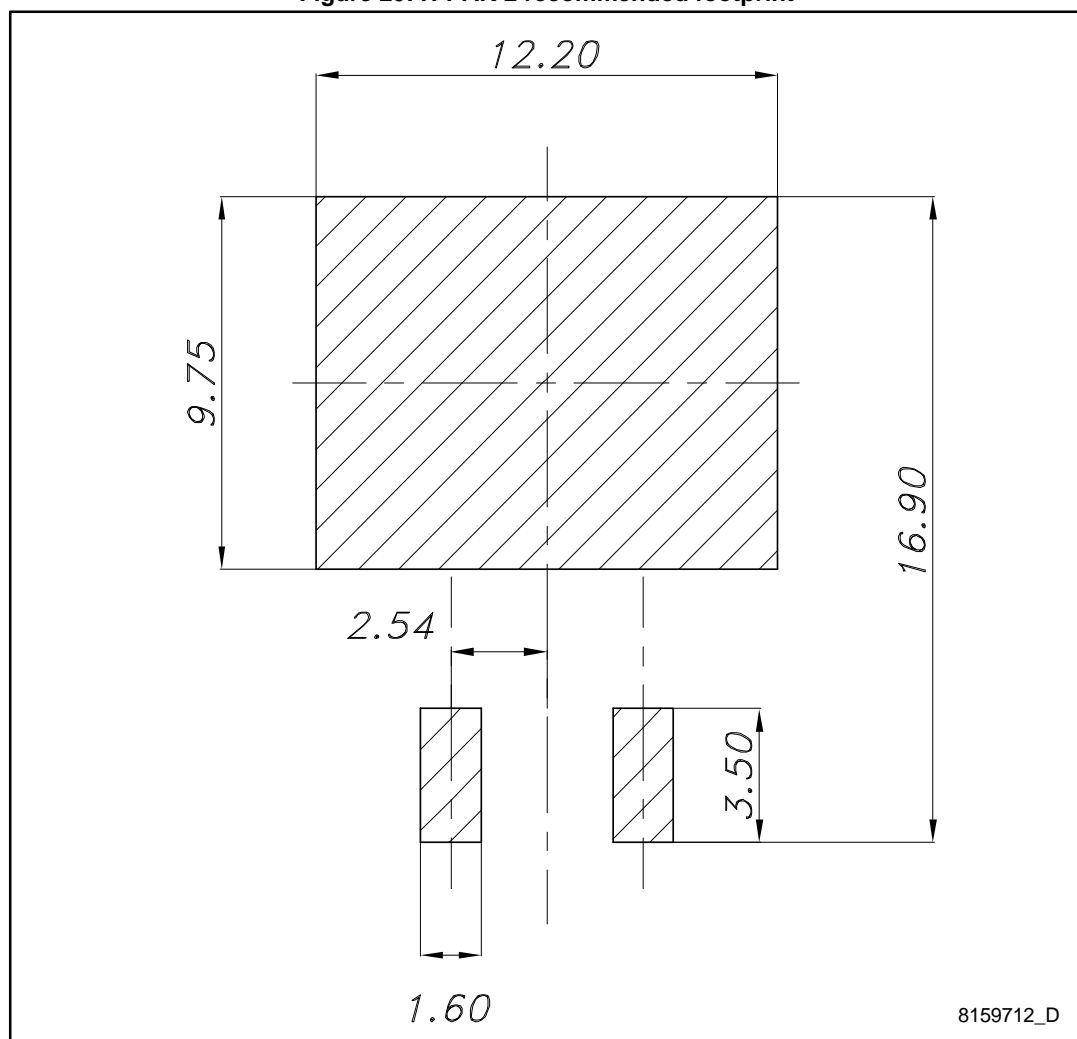
Figure 19: H²PAK-2 package outline

Table 8: H²PAK-2 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30	-	4.80
A1	0.03		0.20
C	1.17		1.37
e	4.98		5.18
E	0.50		0.90
F	0.78		0.85
H	10.00		10.40
H1	7.40		7.80
L	15.30		15.80
L1	1.27		1.40
L2	4.93		5.23
L3	6.85		7.25
L4	1.5		1.7
M	2.6		2.9
R	0.20		0.60
V	0°		8°

Figure 20: H²PAK-2 recommended footprint

5 Packing information

Figure 21: Tape outline

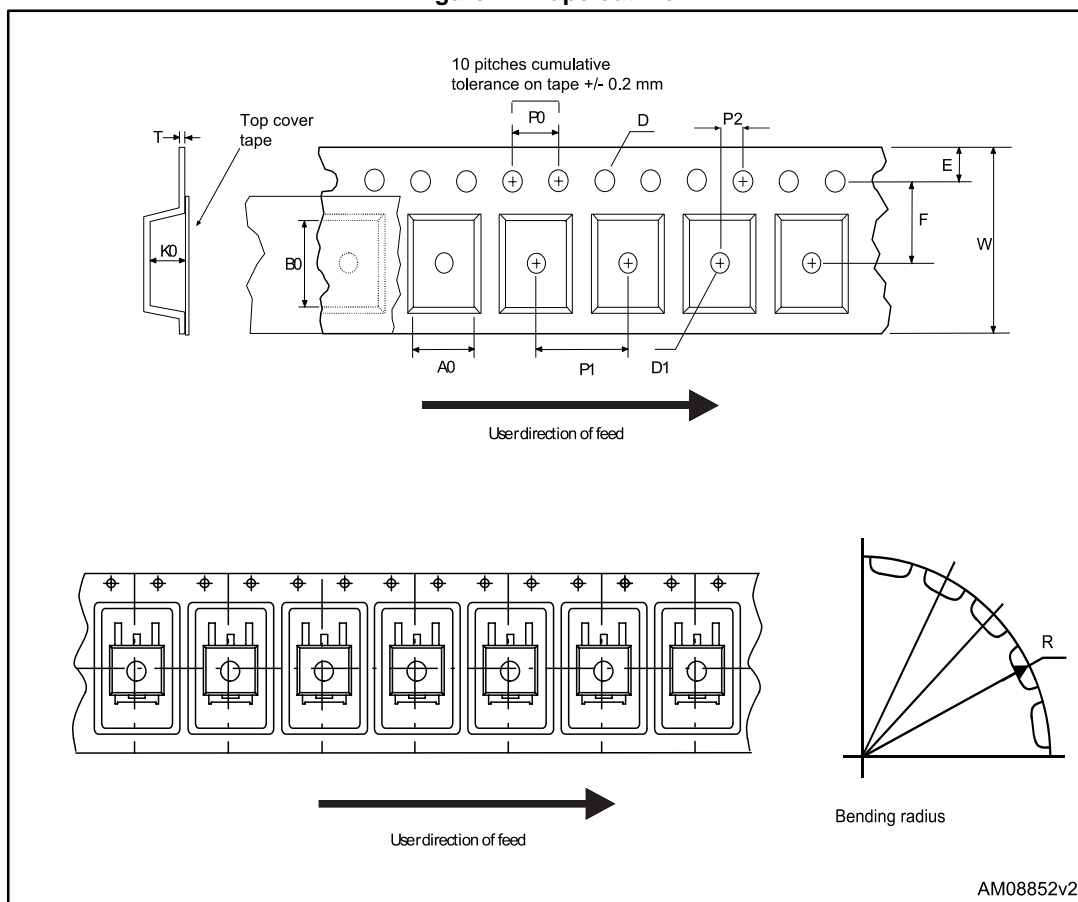


Figure 22: Reel outline

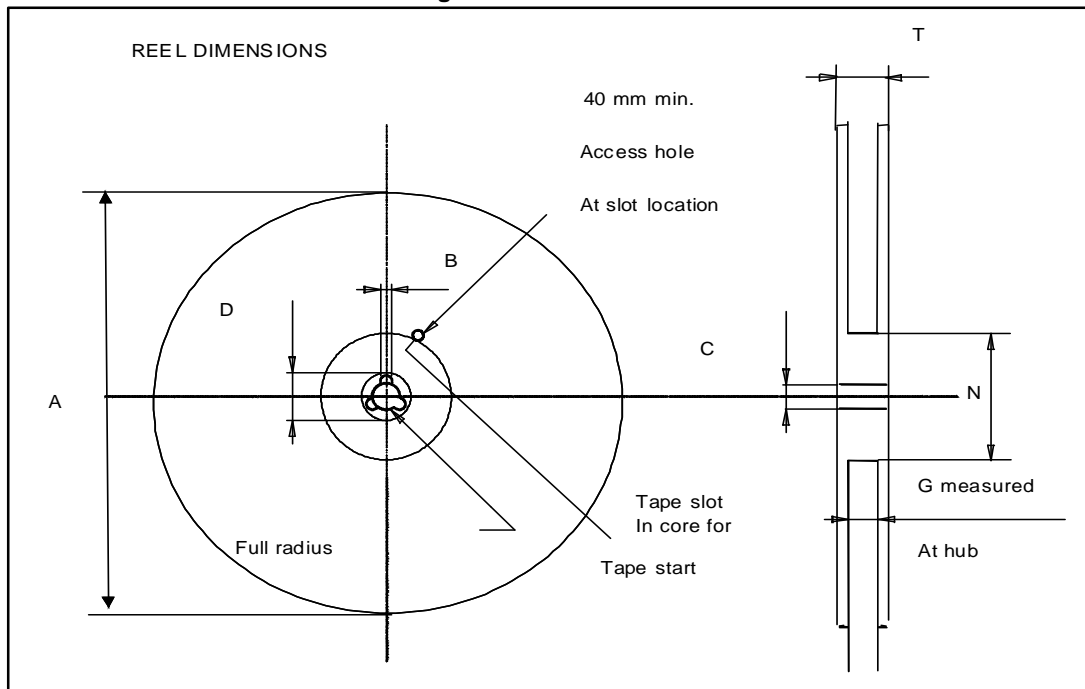


Table 9: Tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

6 Revision history

Table 10: Document revision history

Date	Revision	Changes
05-Jun-2015	1	First release.

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